

SM5611/SM5612 OEM Pressure, Constant Current DIP OEM Pressure, Constant Voltage DIP

OEM Pressure Transducer Fully Temperature Compensated and Calibrated

DUAL-IN-LINE PACKAGE

DESCRIPTION

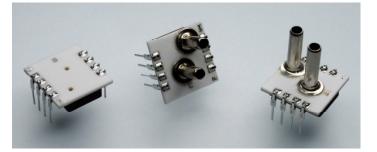
The **SM5600** Series of OEM pressure sensors are fully calibrated, temperature compensated pressure sensors in dual inline packages for printed circuit board mounting. These sensors offer improved performance as well as the option for either constant current or constant voltage excitation. Ultra-low pressure ranges are also available (see **SM5651/SM5652** datasheet), resulting in the broadest selection of standard pressure ranges in the industry.

The SM5600 Series pressure sensors are constructed by attaching a highly stable piezoresistive pressure sensor chip to a ceramic substrate. Thick film resistors on the ceramic are laser trimmed during manufacturing to provide zero offset calibration, temperature compensation for zero offset, and temperature compensation for sensitivity. In the Model SM5611, an additional resistor is trimmed to normalize the output of an external differential amplifier to provide span calibration when the sensor is driven by a constant current supply. In the Model SM5612, a constant voltage supply can be used and the normalized output span of each sensor can then be easily amplified.

The model **SM5611** is designed for constant current excitation.

The model **SM5612** is designed for constant voltage excitation.

Various pressure port configurations are available for flexibility in matching this product to specific applications.



FEATURES

- 15, 30, 60, and 100 PSI FS Ranges Available
- Constant voltage and constant current versions
- Easy to use dual in-line package (DIP)
- Wide 0-60 °C compensated temperature range
- Span calibration to ±2%
- Zero offset calibration
- High performance, stable packaged silicon chip
- Gage, differential, and absolute pressure configurations

APPLICATIONS

- Barometric Pressure
- Medical Instrumentation
- Environmental Control
- Altimeters
- Automotive Diagnostics
- Appliances

40SP5003.01



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CHARACTERISTICS FOR SM5611/SM5612 - SPECIFICATIONS

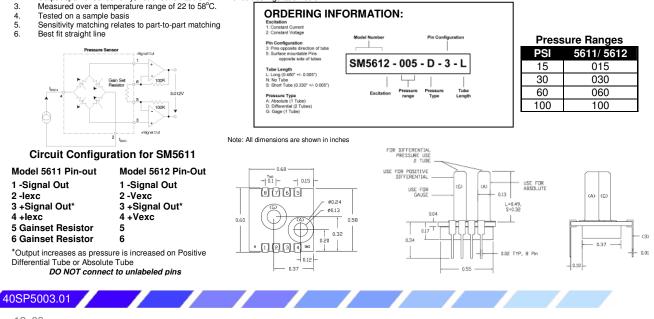
Test Conditions: Model SM5611 w/excitation = 1.500mA @ 25°C, Model SM5612 w/excitation = 10.00Vdc @ 25°C, unless otherwise specified. All parameters below for differential and absolute parts are defined for top side only. All parameters below for gage parts are defined for back side only

	Min.	Тур.	Max.	Units	Notes
Excitation					
Current (SM5611)	>0	1.50	3.00	mA	
Voltage (SM5612)	>0	10.00	20.00	V	
Output					
Span (SM5611)	75.0	105.0	150.0	mV	1, 2
Span (SM5612)	39.5	40.0	40.5	mV	1
Offset	-2.00	±0.20	2.00	mV	
Temperature Performance					
TC Span	-0.5	±0.2	0.5	%FS	2
TC Offset	-0.5	±0.2	0.5	%FS	2
Temp Hysteresis		±0.1		%FS	4
Accuracy					
Linearity	-0.10	±0.05	0.10	%FS	5, 6
Repeatability	-0.10	±0.05	0.10	%FS	4
Pressure Hysteresis	-0.10	±0.05	0.10	%FS	4
Sensitivity Matching	-2.00	±0.20	+2.00	%FS	1, 6, 4
Impedance (SM5611)					
Z Input	1.80	3.00	3.80	kΩ	
Z Output	2.70	3.30	3.80	kΩ	
Impedance (SM5612)					
Z Input	4.50	8.00	25.00	kΩ	
Z Output	2.00	2.50	3.80	kΩ	
Temperature Range				•	
Calibration	0		+60	°C	2
Operating	-40		+125	°C	4
Storage	-40		+125	°C	4
Dynamic Characteristics			•	-	1
Die Proof Pressure	3X or 225 PSI.	whichever is less		FS Pressure	4
Die Burst Pressure	5X or 225 PSI, whichever is less			FS Pressure	4

Notes 1

Positive Pressure is defined as entry on the bottom side of the die; gain, during factory calibration, is set using negative pressure Output span of sensor only, not of schematic shown in circuit configuration below

2.



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